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600V, 3.3A, 1.4| N-Channel Power MOSFET

TO-252 (DPAK)



TO-251 (IPAK)



Pin Definition:

- 1. Gate 2. Drain
- 3. Source

Key Parameter Performance

Parameter	Value	Unit
$V_{ t DS}$	600	V
R _{DS(on)} (max)	1.4	
Q_g	7.7	nC

Features

- ✓ Super-Junction technology
- ∠ High performance due to small figure-of-merit
- ∠ High ruggedness performance
- ∠ High commutation performance

Application

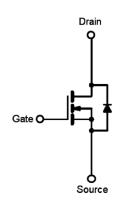
- ∠ Power Supply
- ∠ Lighting

Ordering Information

Part No.	Package	Packing
TSM60N1R4CH C5G	TO-251	75pcs / Tube
TSM60N1R4CP ROG	TO-252	2.5kpcs / 13_Reel

Note: `G_denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	600	V
Gate-Source Voltage	V_{GS}	±30	V
Continuous Drain Current (Note 1) $T_C = 25^{\circ}C$	I _D	3.3	Α
Pulsed Drain Current (Note 2)	I _{DM}	9.9	Α
Total Power Dissipation @ T _C = 25°C	P _{DTOT}	38	W
Single Pulsed Avalanche Energy (Note 3)	E _{AS}	64	mJ
Single Pulsed Avalanche Current (Note 3)	I _{AS}	1.6	Α
Operating Junction and Storage Temperature Range	T _J , T _{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	R∌⊎c	3.3	°C/W
Junction to Ambient Thermal Resistance	R _{∄JA}	62	°C/W





600V, 3.3A, 1.4| N-Channel Power MOSFET

 $\textbf{Electrical Specifications} \ (T_{\text{C}} = 25^{\circ}\text{C unless otherwise noted})$

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static (Note 4)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	600			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	2	3	4	V
Gate Body Leakage	$V_{GS} = \pm 30 V, V_{DS} = 0 V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 600V, V_{GS} = 0V$	I _{DSS}			1	μΑ
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 2A$	R _{DS(ON)}	1	0.88	1.4	
Dynamic (Note 5)						
Total Gate Charge	$V_{DS} = 380V, I_{D} = 3.3A,$ $V_{GS} = 10V$	Q_g	1	7.7		_
Gate-Source Charge		Q_{gs}		1.9		nC
Gate-Drain Charge		Q_{gd}		2.8		
Input Capacitance	$V_{DS} = 100V, V_{GS} = 0V,$	C _{iss}		370		pF
Output Capacitance	f = 1.0MHz	C _{oss}		34		
Gate Resistance	f = 1MHz, open drain	R_g		3.4		
Switching (Note 6)						
Turn-On Delay Time		t _{d(on)}		14		
Turn-On Rise Time	$\begin{aligned} &V_{DD} = 380V, \\ &R_{GEN} = 25 \;, \\ &I_{D} = 3.3A, V_{GS} = 10V, \end{aligned}$	t _r		22		
Turn-Off Delay Time		t _{d(off)}		24		ns
Turn-Off Fall Time		t _f		20		
Source-Drain Diode (Note 4)						
Forward On Voltage	$I_S = 3.3A, V_{GS} = 0V$	V _{SD}			1.4	V
Reverse Recovery Time	V _B = 200V, I _S = 2A	t _{rr}		163		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\approx$	Q _{rr}		1		æ

Notes:

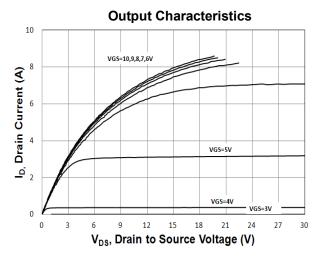
- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. L = 50mH, $I_{AS} = 1.6A$, $V_{DD} = 50V$, $R_G = 25$, Starting $T_J = 25$ °C
- 4. Pulse test: PW #300μs, duty cycle #2%
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.



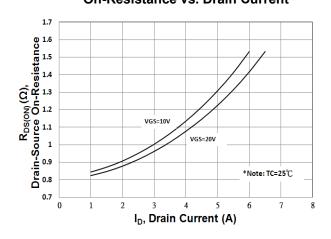


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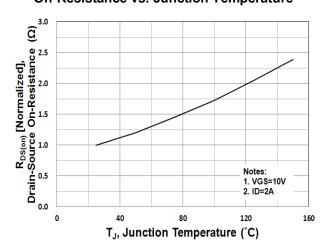
Electrical Characteristics Curves



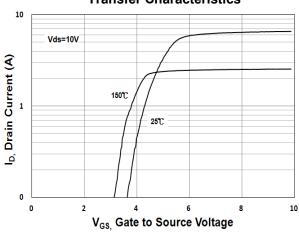
On-Resistance vs. Drain Current



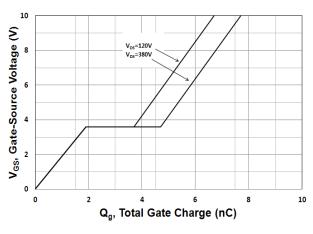
On-Resistance vs. Junction Temperature



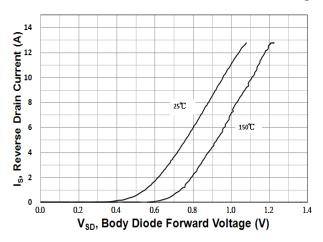
Transfer Characteristics



Gate-Source Voltage vs. Gate Charge



Source-Drain Diode Forward Current vs. Voltage



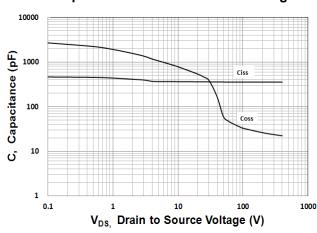




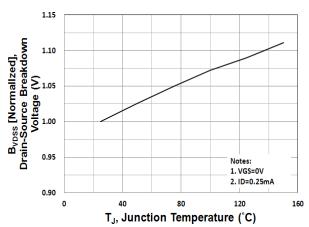
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Electrical Characteristics Curves

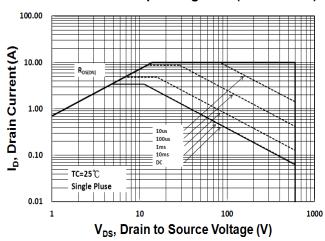
Capacitance vs. Drain-Source Voltage



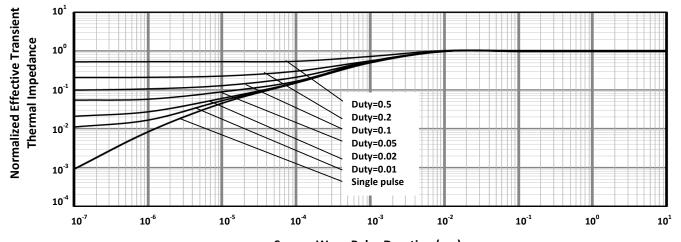
BV_{DSS} vs. Junction Temperature



Maximum Safe Operating Area (DPAK/IPAK)



Normalized Thermal Transient Impedance, Junction-to-Case (DPAK/IPAK)

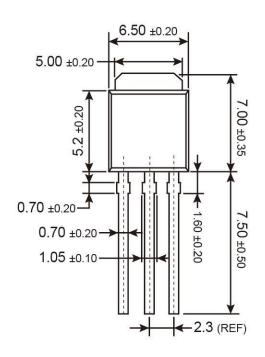


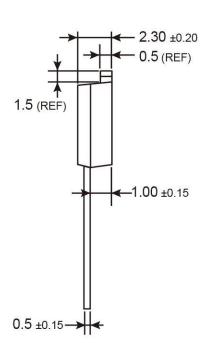
Square Wave Pulse Duration (sec)





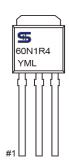
TO-251 (IPAK) Mechanical Drawing





Unit: Millimeter

Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product
(O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep,
X=Oct, Y=Nov, Z=Dec)

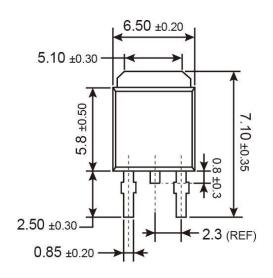
L = Lot Code

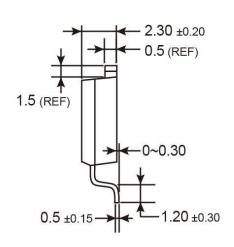




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TO-252 (DPAK) Mechanical Drawing





Unit: Millimeters

Marking Diagram



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